MSB92WT1G, MSB92AWT1G

PNP Silicon General Purpose High Voltage Transistor

This PNP Silicon Planar Transistor is designed for general purpose amplifier applications. This device is housed in the SC-70/SOT-323 package which is designed for low power surface mount applications.

Features

• These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS (T_A = 25°C)

Rating	Symbol	Value	Unit
Collector-Base Voltage	V _{(BR)CBO}	-300	Vdc
Collector-Emitter Voltage	V _{(BR)CEO}	-300	Vdc
Emitter-Base Voltage	V _{(BR)EBO}	-5.0	Vdc
Collector Current - Continuous	I _C	500	mAdc
Electrostatic Discharge	ESD	MBM > 16,000, MM > 2,000	V

THERMAL CHARACTERISTICS

Rating	Symbol	Max	Unit
Power Dissipation (Note 1)	P _D	150	mW
Junction Temperature	TJ	150	°C
Storage Temperature Range	T _{stg}	-55 to +150	°C

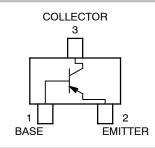
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

 Device mounted on a FR-4 glass epoxy printed circuit board using the minimum recommended footprint.



ON Semiconductor®

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SC-70 (SOT-323) CASE 419 STYLE 3

MARKING DIAGRAM



xx = Device Code x= 2D or D2

M = Date Code*

= Pb-Free Package

(Note: Microdot may be in either location)
*Date Code orientation may vary depending
upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
MSB92WT1G	SC-70/ SOT-323 (Pb-Free)	3000/Tape & Reel
MSB92AWT1G	SC-70/ SOT-323 (Pb-Free)	3000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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MSB92WT1G, MSB92AWT1G

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Min	Max	Unit	
Collector-Emitter Breakdown Voltage (I _C = -1.0 mAdc, I _B = 0)	V _{(BR)CEO}	-300	-	Vdc	
Collector-Base Breakdown Voltage ($I_C = -100 \mu Adc, I_E = 0$)	V _{(BR)CBO}	-300	-	Vdc	
Emitter-Base Breakdown Voltage $(I_E = -100 \ \mu Adc, I_E = 0)$	V _{(BR)EBO}	-5.0	-	Vdc	
Collector-Base Cutoff Current (V _{CB} = -200 Vdc, I _E = 0)	I _{CBO}	-	-0.25	μΑ	
Emitter-Base Cutoff Current $(V_{EB} = -3.0 \text{ Vdc}, I_B = 0)$	I _{EBO}	-	-0.1	μΑ	
DC Current Gain (Note 2) MSB92WT1: $(V_{CE} = -10 \text{ Vdc}, I_{C} = -1.0 \text{ mAdc})$ MSB92AWT1: $(V_{CE} = -10 \text{ Vdc}, I_{C} = -1.0 \text{ mAdc})$ $(V_{CE} = -10 \text{ Vdc}, I_{C} = -10 \text{ mAdc})$ $(V_{CE} = -10 \text{ Vdc}, I_{C} = -30 \text{ mAdc})$	h _{FE1} h _{FE1} h _{FE2} h _{FE3}	25 120 40 25	- 200 - -	-	
Collector-Emitter Saturation Voltage (Note 2) (I _C = -20 mAdc, I _B = -2.0 mAdc)	V _{CE(sat)}	-	-0.5	Vdc	
Base-Emitter Saturation Voltage (I _C = -20 mAdc, I _B = -2.0 mAdc)	V _{BE(sat)}	-	-0.9	Vdc	
SMALL SIGNAL CHARACTERISTICS					
Current - Gain - Bandwidth Product (I _C = -10 mAdc, V _{CE} = -20 Vdc, f = 20 MHz)	f _T	50	-	MHz	
Collector-Base Capacitance (V _{CB} = -20 Vdc, I _E = 0, f = 1.0 MHz)	C _{cb}	-	6.0	pF	

^{2.} Pulse Test: Pulse Width ≤ 300 μs, D.C. ≤ 2%.

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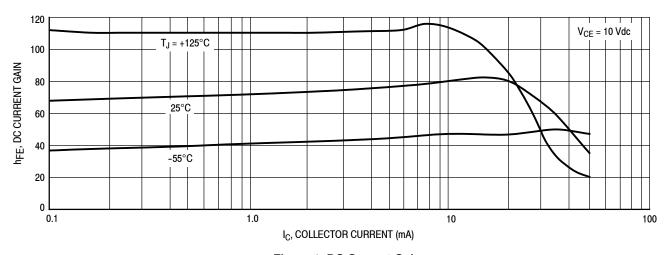


Figure 1. DC Current Gain

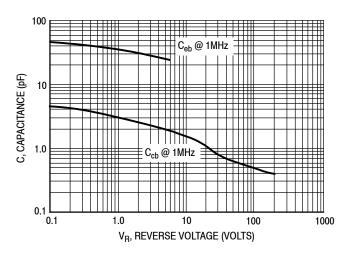


Figure 2. Capacitance

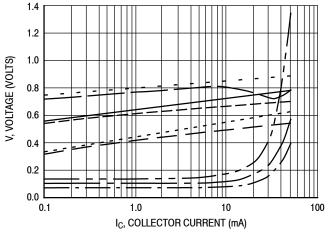
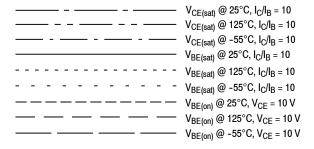


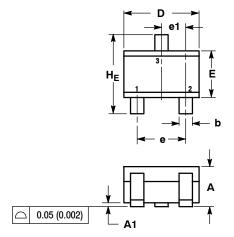
Figure 3. "ON" Voltages



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PACKAGE DIMENSIONS

SC-70 (SOT-323) CASE 419-04 ISSUE N



NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.80	0.90	1.00	0.032	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A2		0.70 REF			0.028 REF	
b	0.30	0.35	0.40	0.012	0.014	0.016
С	0.10	0.18	0.25	0.004	0.007	0.010
D	1.80	2.10	2.20	0.071	0.083	0.087
E	1.15	1.24	1.35	0.045	0.049	0.053
е	1.20	1.30	1.40	0.047	0.051	0.055
e1		0.65 BSC			0.026 BSC	;
L	0.20	0.38	0.56	0.008	0.015	0.022
HE	2.00	2.10	2.40	0.079	0.083	0.095

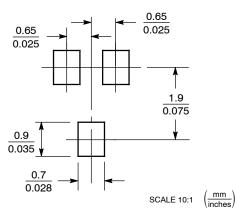
A2 A2

STYLE 3:

PIN 1. BASE 2. EMITTER

3. COLLECTOR

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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